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**** CONTINUING DATA *******

This application is a 371 of PCT/JP02/13735 12/26/2002 (M)

**** FOREIGN APPLICATIONS *******

JAPAN 2001-393056 12/26/2001 (M)

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 3	TOTAL CLAIMS 7	INDEPENDENT CLAIMS 2
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after				
Verified and Acknowledged Examiner's Signature: <i>Mark J</i> Initials: <i>MJ</i>				

ADDRESS

38834

TITLE

Group III-nitride semiconductor substrate and its manufacturing method

FILING FEE RECEIVED 1340	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees
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